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AMENDMENT UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
GROUP 2815
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q58705

Yoji OKAZAKI, et al.

Appln. No.: 09/659,456

Group Art Unit: 2815

Confirmation No.: 5835

Examiner: Joseph H. Nguyen

Filed: September 11, 2000

For: LASER APPARATUS IN WHICH GaN-BASED COMPOUND SURFACE-EMITTING
SEMICONDUCTOR ELEMENT IS EXCITED WITH GaN-BASED COMPOUND
SEMICONDUCTOR LASER ELEMENT

AMENDMENT UNDER 37 C.F.R. § 1.116

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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TECHNOLOGY CENTER 280C

Sir:

In response to the Office Action dated May 15, 2003, please amend the above-identified application as follows on the accompanying pages.

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